Silicon Controlled Rectifiers Reverse Blocking Triode Thyristors

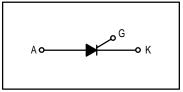
PNPN devices designed for high volume, line-powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits. Supplied in an inexpensive plastic TO-226AA package which is readily adaptable for use in automatic insertion equipment.

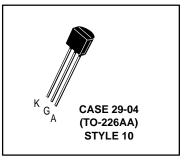
- Sensitive Gate Trigger Current 200 μA Maximum
- Low Reverse and Forward Blocking Current 100 μA Maximum, T_C = 125°C
- Low Holding Current 5 mA Maximum
- Glass-Passivated Surface for Reliability and Uniformity



*Motorola preferred devices

SCRs 0.8 AMPERE RMS 100 thru 600 VOLTS





MAXIMUM RATINGS (T_J = 25° C unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Forward and Reverse Blocking Voltage(1) ($T_J = 25$ to 125° C, $R_{GK} = 1 \text{ k}\Omega$ MCR100-3 MCR100-4 MCR100-6 MCR100-8	VDRM and ^V RRM	100 200 400 600	Volts
Forward Current RMS (See Figures 1 & 2) (All Conduction Angles)	IT(RMS)	0.8	Amps
Peak Forward Surge Current, T _A = 25°C (1/2 Cycle, Sine Wave, 60 Hz)	ITSM	10	Amps
Circuit Fusing Considerations (t = 8.3 ms)	l ² t	0.415	A ² s
Peak Gate Power — Forward, $T_A = 25^{\circ}C$	PGM	0.1	Watts
Average Gate Power — Forward, $T_A = 25^{\circ}C$	PGF(AV)	0.01	Watt
Peak Gate Current — Forward, T _A = 25°C (300 μs, 120 PPS)	^I GFM	1	Amp
Peak Gate Voltage — Reverse	VGRM	5	Volts
Operating Junction Temperature Range @ Rated VRRM and VDRM	Тј	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
Lead Solder Temperature (< 1/16" from case, 10 s max)		+230	°C

1. VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Preferred devices are Motorola recommended choices for future use and best overall value.



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{θJC}	75	°C/W
Thermal Resistance, Junction to Ambient	R _{θJA}	200	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C, R_{GK} = 1 k Ω unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit
Peak Forward or Reverse Blocking Current (V _{AK} = Rated V _{DRM} or V _{RRM})	T _C = 25°C T _C = 125°C	IDRM, IRRM	=	10 100	μA μA
Forward "On" Voltage(1) (I _{TM} = 1 A Peak @ T _A = 25°C)		V _{TM}	-	1.7	Volts
Gate Trigger Current (Continuous dc) ⁽²⁾ (Anode Voltage = 7 Vdc, R _L = 100 Ohms)	$T_C = 25^{\circ}C$	IGT	—	200	μA
Gate Trigger Voltage (Continuous dc) (Anode Voltage = 7 Vdc, R _L = 100 Ohms) (Anode Voltage = Rated V _{DRM} , R _L = 100 Ohms)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$ $T_{C} = 125^{\circ}C$	VGT	— — 0.1	0.8 1.2 —	Volts
Holding Current (Anode Voltage = 7 Vdc, initiating current = 20 mA)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$	lΗ	—	5 10	mA

1. Forward current applied for 1 ms maximum duration, duty cycle \leq 1%.

2. R_{GK} current is not included in measurement.

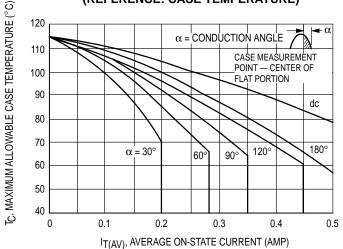
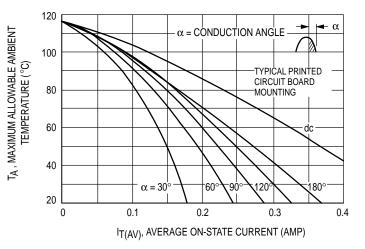
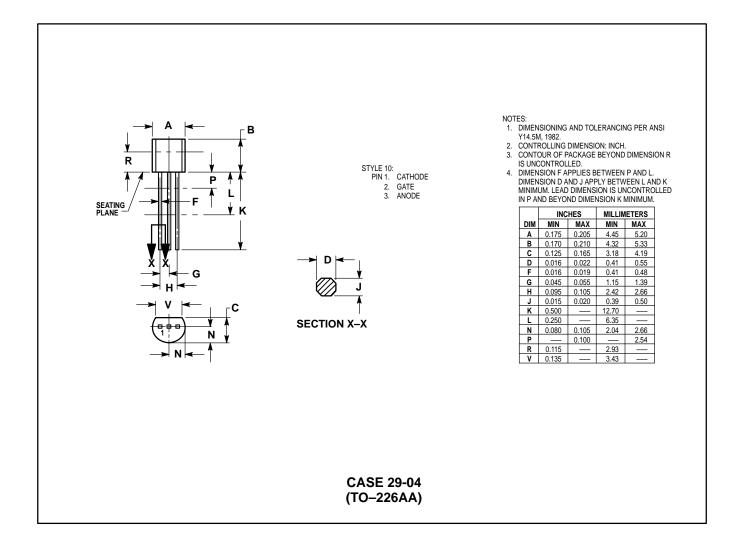


FIGURE 1 – MCR100-7, MCR100-8 CURRENT DERATING (REFERENCE: CASE TEMPERATURE)

FIGURE 2 – MCR100-7, MCR100-8 CURRENT DERATING (REFERENCE: AMBIENT TEMPERATURE)



PACKAGE DIMENSIONS



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